



# ***AOS Semiconductor Product Reliability Report***

**AOZ6682CI/AOZ6683CI**, rev A

**Plastic Encapsulated Device**

**ALPHA & OMEGA Semiconductor, Inc**

**[www.aosmd.com](http://www.aosmd.com)**

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This AOS product reliability report summarizes the qualification result for AOZ6682/83CI. Accelerated environmental tests are performed on a specific sample size, and then followed by electrical test at end point. Review of final electrical test result confirms that AOZ6682/83CI passes AOS quality and reliability requirements. The released product will be categorized by the process family and be routine monitored for continuously improving the product quality.

## I. Reliability Stress Test Summary and Results

| Test Item                   | Test Condition   | Time Point                | Total Sample Size | Number of Failures | Reference Standard |
|-----------------------------|--|---------------------------|-------------------|--------------------|--------------------|
| HTOL                        | $T_J = 125^{\circ}\text{C}$ ,<br>$V_{IN} = V_{IN\ max}$                            | 168 / 500 /<br>1000 hours | 231 pcs           | 0                  | JESD22-A108        |
| Preconditioning<br>(Note A) | $T_A = 85^{\circ}\text{C}$ , RH = 85% +<br>3 cycle reflow @ 260°C<br>(MSL 1)       | -                         | 924 pcs           | 0                  | JESD22-A113        |
| HAST                        | $T_A = 130^{\circ}\text{C}$ , RH = 85%,<br>P = 33.3psia,<br>$V_{IN} = V_{IN\ max}$ | 96 hours                  | 231 pcs           | 0                  | JESD22-A110        |
| Autoclave                   | $T_A = 121^{\circ}\text{C}$ , RH = 100%,<br>P = 29.7psia                           | 168 hours                 | 231 pcs           | 0                  | JESD22-A102        |
| Temperature Cycle           | $T_A = -65^{\circ}\text{C}$ to 150°C,<br>air to air                                | 1000cycles                | 231 pcs           | 0                  | JESD22-A104        |
| HTSL                        | $T_A = 150^{\circ}\text{C}$  | 1000 hours                | 231 pcs           | 0                  | JESD22-A103        |

**Note:** The reliability data presents total of available generic data up to the published date.

Note A: MSL (Moisture Sensitivity Level) 1 based on J-STD-020

## II. Reliability Evaluation

Taking the result of HTOL AOZ6682CI & AOZ6683CI Lots the total device stress time

**FIT rate (per billion): 15.26 FIT**  
**MTTF = 7480 years**

The presentation of FIT rate for the individual product reliability is restricted by the actual burn-in sample size. Failure Rate Determination is based on JEDEC Standard JESD 85. FIT means one failure per billion hours.

**Failure Rate** =  $\text{Chi}^2 \times 10^9 / [2 (N) (H) (Af)] = 15.26$

**MTTF** =  $10^9 / \text{FIT} = 7480$  years

**Chi<sup>2</sup>** = Chi Squared Distribution, determined by the number of failures and confidence interval

**N** = Total Number of units from burn-in tests

**H** = Duration of burn-in testing

**Af** = Acceleration Factor from Test to Use Conditions ( $E_a = 0.7\text{eV}$  and  $T_{use} = 55^{\circ}\text{C}$ )

Acceleration Factor **[Af]** =  $\text{Exp} [E_a / k (1/T_{J\ u} - 1/T_{J\ s})]$

**Acceleration Factor ratio list:**

|           | 55 deg C  | 70 deg C  | 85 deg C   | 100 deg C  | 115 deg C  | 125 deg C |
|-----------|-----------|-----------|------------|------------|------------|-----------|
| <b>Af</b> | <b>77</b> | <b>26</b> | <b>9.8</b> | <b>3.9</b> | <b>1.7</b> | <b>1</b>  |

**T<sub>J s</sub>** = Stressed junction temperature in degree (Kelvin),  $K = C + 273.16$

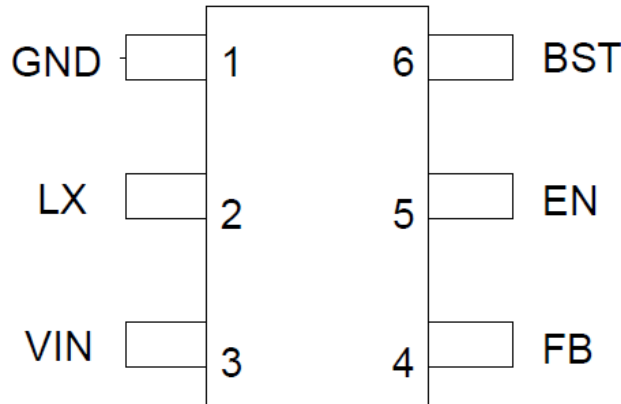
**T<sub>J u</sub>** = The use junction temperature in degree (Kelvin),  $K = C + 273.16$

**k** = Boltzmann's constant,  $8.617164 \times 10^{-5}\text{eV} / \text{K}$

### III. ESD and Latch Up Test Results

| Test   | Test Conditions                             | Total Sample Size | Number of Failures | Reference Standard |
|--|---|-------------------|--------------------|--------------------|
| Electrostatic Discharge Human Body Model     | T <sub>A</sub> = 25°C, +/-2kV               | 3                 | 0                  | JESD-A114          |
| Electrostatic Discharge Charged Device Model | T <sub>A</sub> = 25°C, +/-1kV               | 3                 | 0                  | JESD-C101          |
| Latch Up                                     | T <sub>A</sub> = 25°C,<br>+/-100mA, 1.5x OV | 6                 | 0                  | JESD78             |
| Latch Up                                     | T <sub>A</sub> = 85°C,<br>+/-100mA, 1.5x OV | 6                 | 0                  | JESD78             |

(1) ATE results are used to determine PASS/FAIL. Parametric shift<10%.



*Top Transparent View*

**6-pin SOT23-6**